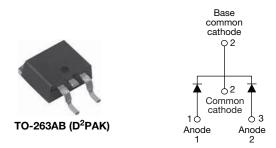
Vishay Semiconductors

RoHS

FREE

High Performance Schottky Rectifier, 2 x 15 A



www.vishay.com

PRODUCT SUMMARY							
Package	TO-263AB (D ² PAK)						
I _{F(AV)}	2 x 15 A						
V _R	30 V						
V _F at I _F	0.47 V						
I _{RM} max.	183 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	13 mJ						

FEATURES

- 150 °C T_J operation
- · Center tap configuration
- Very low forward voltage drop
- · High frequency operation
- COMPLIANT High purity, high temperature epoxy HALOGEN encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	30	А					
V _{RRM}		30	V					
I _{FSM}	t _p = 5 μs sine	1100	A					
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.34	V					
TJ	Range	-55 to +150	C°					

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB3030CTLPbF	UNITS						
Maximum DC reverse voltage	V _R	- 30	V						
Maximum working peak reverse voltage	V _{RWM}		V						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average per leg		50 % duty cycle at T _C = 121 °C	rectangular waveform	15				
See fig. 5 per device	I _{F(AV)}		30	А				
Maximum peak one cycle non-repetitive surge current per leg		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	1100	A			
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	360				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.9 mH		13	mJ			
Repetitive avalanche current per leg		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А			

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VS-MBRB3030CTLPbF



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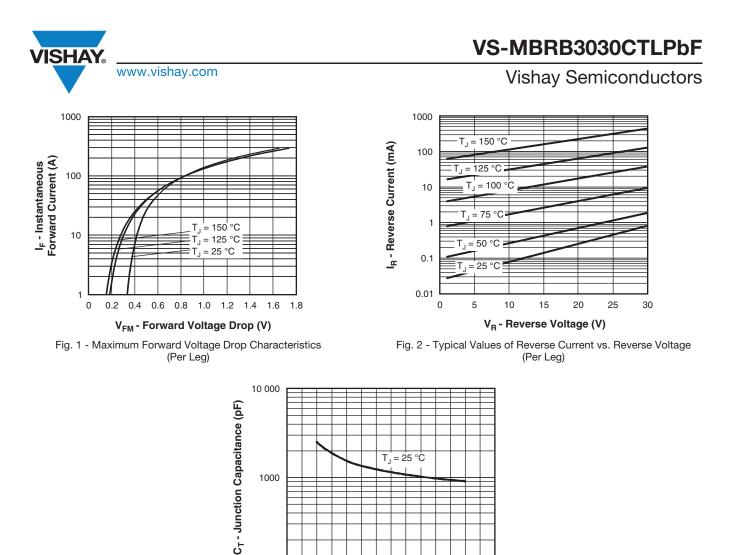
ELECTRICAL SPECIFICATIONS

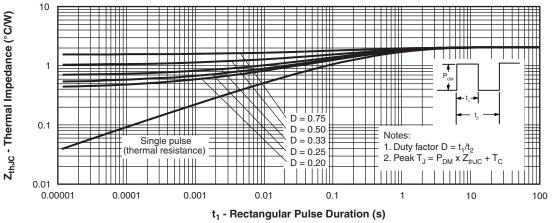
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		15 A	T _{.1} = 25 °C	0.47	V			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	30 A	1j=25 C	0.55				
See fig. 1	VFM (")	15 A	T 105 %C	0.34				
		30 A	T _J = 125 °C	0.45				
Maximum reverse leakage current per leg	1 (1)	T _J = 25 °C)/ Detect)/	2	mA			
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	183				
Threshold voltage	V _{F(TO)}	$T_J = T_J$ maximum		0.22	V			
Forward slope resistance	r _t			6.76	mΩ			
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	2840	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistance,	per leg	Р	DC operation	2.0				
junction to case	per package	R _{thJC}	DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0,			
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style D ² PAK	MBRB30	30CTL			





100 L 0

5

10

15

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

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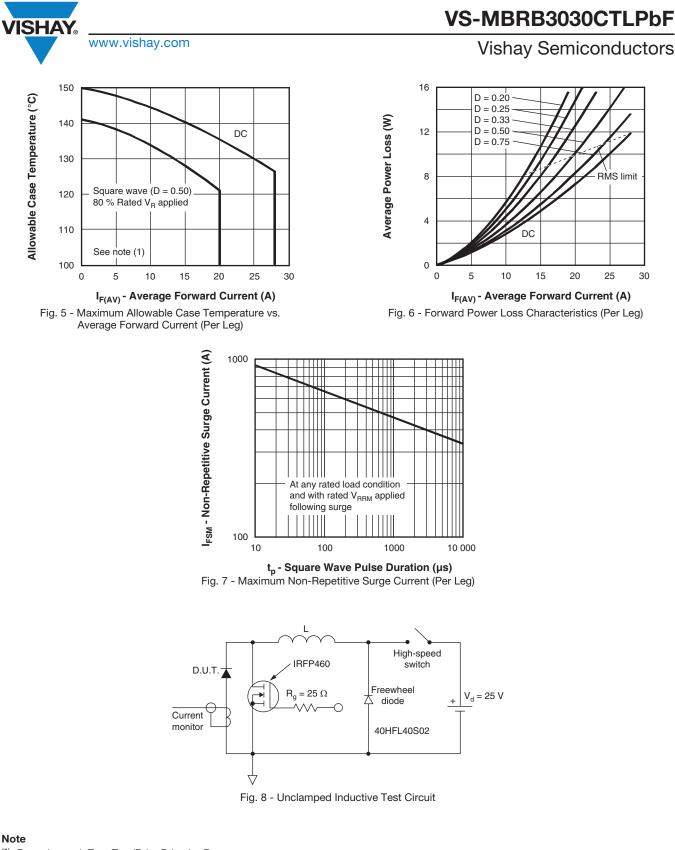
V_R - Reverse Voltage (V)

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Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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L

TRL

1 - Vishay Semiconductors product

В

2 - Schottky MBR series
3 - B = D²PAK
4 - Current rating (30 = 30 A)
5 - Voltage rating (30 = 30 V)
6 - CT = center tap (dual)

30

30

СТ

- $L = Iow V_F$
 - None = tube (50 pieces)
 - TRL = tape and reel (left oriented for D²PAK only)
 - TRR = tape and reel (right oriented for D²PAK only)
- PbF = lead (Pb)-free (for D²PAK tube)
 - P = lead (Pb)-free (for D²PAK TRR and TRL)

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

PbF

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ORDERING INFORMATION TABLE

Device code

VS-

1

7

8

9

MBR

(2)

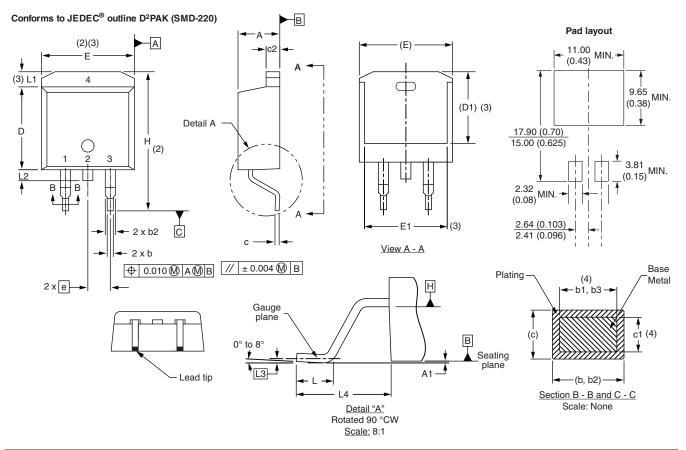
Outline Dimensions



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIN	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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